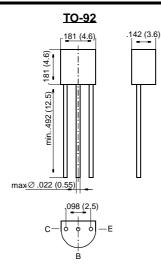
BC556 THRU BC559

Small Signal Transistors (PNP)



Dimensions in inches and (millimeters)

FEATURES

- PNP Silicon Epitaxial Planar Transistors for switching and AF amplifier applications.
- These transistors are subdivided into three groups A, B and C according to their current gain. The type BC556 is available in groups A and B, however, the types BC557 and BC558 can be supplied in all three groups. The BC559 is a low-noise type available in all three groups. As complementary types, the NPN transistors BC546 ... BC549 are recommended.
- On special request, these transistors are also manufactured in the pin configuration TO-18.

MECHANICAL DATA

Case: TO-92 Plastic Package **Weight:** approx. 0.18 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

| | | Symbol | Value | Unit |
|---|--------------------------------|---|-------------------|-------------|
| Collector-Base Voltage | BC556 BC557 BC558, BC559 | -V _{CBO} -V _{CBO} -V _{CBO} | 80 50 30 | V V V |
| Collector-Emitter Voltage | BC556 BC557 BC558, BC559 | -V _{CES} -V _{CES} -V _{CES} | 80 50 30 | V V V |
| Collector-Emitter Voltage | BC556 BC557 BC558, BC559 | -V _{CEO} -V _{CEO} -V _{CEO} | 65 45 30 | V V V |
| Emitter-Base Voltage | | -V _{EBO} | 5 | V |
| Collector Current | | -I _C | 100 | mA |
| Peak Collector Current | | -I _{CM} | 200 | mA |
| Peak Base Current | | –I _{BM} | 200 | mA |
| Peak Emitter Current | | I _{EM} | 200 | mA |
| Power Dissipation at T _{amb} = 25 °C | | P _{tot} | 500 ¹⁾ | mW |
| Junction Temperature | | Tj | 150 | °C |
| Storage Temperature Range | | T _S | -65 to +150 | °C |



BC556 THRU BC559

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

| | | Symbol | Min. | Тур. | Max. | Unit |
|---|-------------------------|--|------|-----------------------------------|-------------------|----------|
| n-Parameters | | | | | | |
| $t - V_{CE} = 5 V, -I_{C} = 2$ | | | | | | |
| Current Gain | Current Gain Group A | h _{fe} | - | 220 | _ | - |
| | В | h _{fe} | - | 330 | - | - |
| | С | h _{fe} | _ | 600 | _ | - |
| nput Impedance | Current Gain Group A | h _{ie} | 1.6 | 2.7 | 4.5 | kΩ |
| | В | h _{ie} | 3.2 | 4.5 | 8.5 | kΩ |
| O () () () () | C | h _{ie} | 6 | 8.7 | 15 | kΩ |
| Output Admittance | Current Gain Group A | h _{oe} | _ | 18 | 30 | μS |
| | B C | h _{oe} | - | 30 60 | 60 110 | μS μS |
| Reverse Voltage Tran | | h _{oe} | - | 00 | 110 | μΟ |
| tororoo ronago nan | Current Gain Group A | h _{re} | _ | 1.5 [•] 10 ⁻⁴ | _ | _ |
| | B | h _{re} | _ | 2 10-4 | _ | _ |
| | C | h _{re} | _ | 3 10-4 | _ | - |
| | | | | | | |
| DC Current Gain at –V _{CE} = 5 V, –I _C = 1 | IOuA | | | | | |
| $C_{\rm E} = 0.0, C_{\rm E}$ | Current Gain Group A | h _{FE} | _ | 90 | _ | - |
| | B | h _{FE} | _ | 150 | _ | - |
| | C | h _{FE} | _ | 270 | _ | - |
| $t - V_{CE} = 5 V, -I_{C} = 2$ | • | | | - | | |
| | Current Gain Group A | h _{FE} | 110 | 180 | 220 | |
| | В | h _{FE} | 200 | 290 | 450 | |
| | С | h _{FE} | 420 | 500 | 800 | |
| at –V _{CE} = 5 V, –I _C = 1 | 00 mA | | | | | _ |
| | Current Gain Group A | h _{FE} | - | 120 | _ | - |
| | В | h _{FE} | - | 200 | _ | - |
| | С | h _{FE} | - | 400 | - | |
| Thermal Resistance | Junction to Ambient Air | R _{thJA} | - | - | 250 ¹⁾ | K/W |
| Collector Saturation | /oltage | | | | | |
| at –I _C = 10 mA, –I _B = | | -V _{CEsat} | _ | 80 | 300 | mV |
| $at - I_{C} = 100 \text{ mA}, - I_{B}$ | | -V _{CEsat} | _ | 250 | 650 | mV |
| | | 0_000 | | | | |
| Base Saturation Volta | | | | 700 | | |
| at $-I_{C} = 10 \text{ mA}, -I_{B} =$ | 0.5 mA | -V _{BEsat} | - | 700 | - | mV |
| $at - I_{C} = 100 \text{ mA}, - I_{B}$ | = 5 MA | -V _{BEsat} | - | 900 | — | mV |
| Base-Emitter Voltage | | | | | | |
| at $-V_{CE} = 5 \text{ V}, -I_C = 2$ | | –V _{BE} | 600 | 660 | 750 | mV |
| $at - V_{CE} = 5 V, -I_C = 1$ | | | _ | _ | 800 | mV |
| | | | | | - | |
| Collector-Emitter Cut | | . | | | 4- | |
| at $-V_{CE} = 80 V$ | BC556 | -I _{CES} | - | 0.2 | 15 | nA |
| at $-V_{CE} = 50 V$ | BC557 | -I _{CES} | - | 0.2 | 15 | nA |
| at –V _{CE} = 30 V | BC558 | -I _{CES} | - | 0.2 | 15 | nA |
| | 25 °C BC556 | -I _{CES} | - | - | 4 | μA |
| at –V _{CE} = 80 V, T _i = 1 | | | | | | |
| at $-V_{CE} = 80 \text{ V}, \text{ T}_{\text{j}} = 1$ at $-V_{CE} = 50 \text{ V}, \text{ T}_{\text{j}} = 1$ at $-V_{CE} = 30 \text{ V}, \text{ T}_{\text{j}} = 1$ | 25 °C BC557 | –I _{CES} –I _{CES} | - | - | 4 4 | μΑ μΑ |

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.



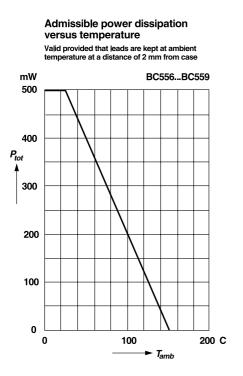
BC556 THRU BC559

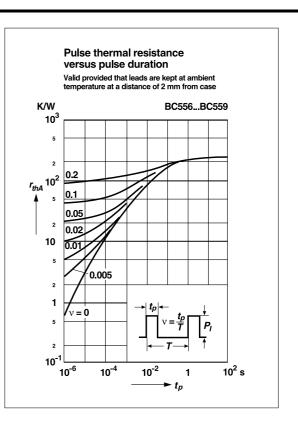
ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

| | Symbol | Min. | Тур. | Max. | Unit |
|---|------------------|------|--------|---------|----------|
| Gain-Bandwidth Product at $-V_{CE} = 5 V$, $-I_{C} = 10 mA$, f = 100 MHz | f _T | - | 150 | - | MHz |
| Collector-Base Capacitance at $-V_{CB} = 10V$, f = 1 MHz | C _{CBO} | _ | _ | 6 | pF |
| Noise Figure at $-V_{CE} = 5 \text{ V}$, $-I_C = 200 \ \mu\text{A}$, $R_G = 2 \ k\Omega$, f = 1 kHz, $\Delta f = 200 \ \text{Hz}$ BC556, BC557, BC558 BC559 | F F | | 2 1 | 10 4 | dB dB |
| Noise Figure at $-V_{CE} = 5 \text{ V}$, $-I_C = 200 \mu\text{A}$, $R_G = 2 k\Omega$, $f = 3015000 \text{ Hz}$ BC559 | F | _ | 1.2 | 4 | dB |

RATINGS AND CHARACTERISTIC CURVES BC556 THRU BC559

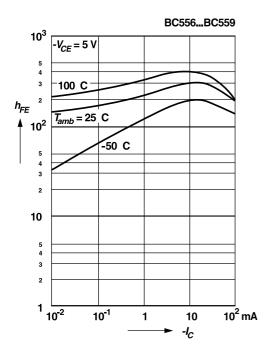




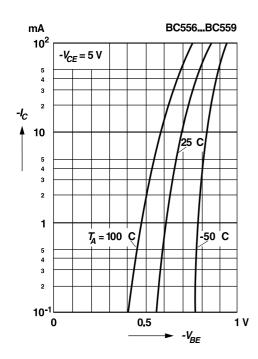


RATINGS AND CHARACTERISTIC CURVES BC556 THRU BC559

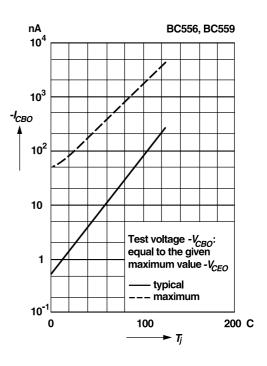
DC current gain versus collector current



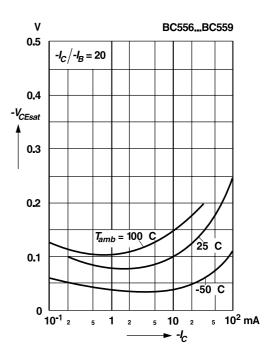
Collector current versus base-emitter voltage



Collector-base cutoff current versus junction temperature



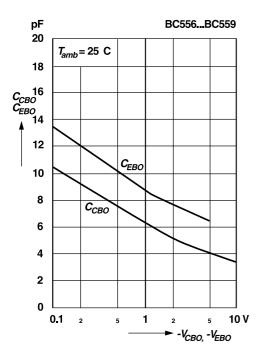
Collector saturation voltage versus collector current



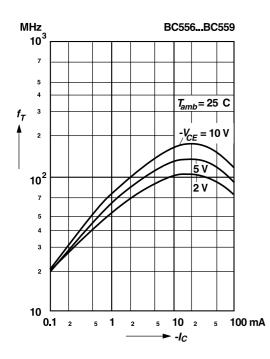


RATINGS AND CHARACTERISTIC CURVES BC556 THRU BC559

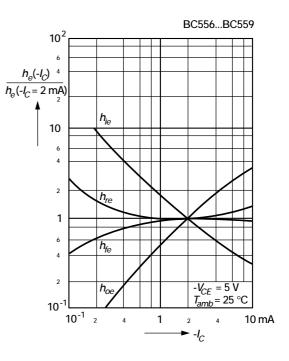
Collector-base capacitance, Emitter-base capacitance versus reverse bias voltage



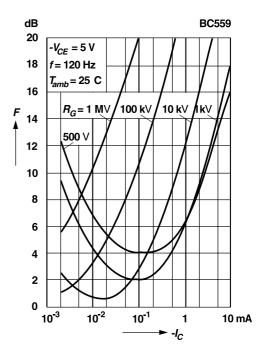
Gain-bandwidth product versus collector current



Relative h-parameters versus collector current

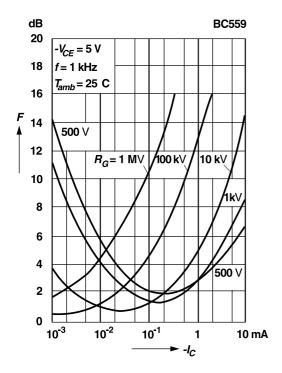


Noise figure versus collector current

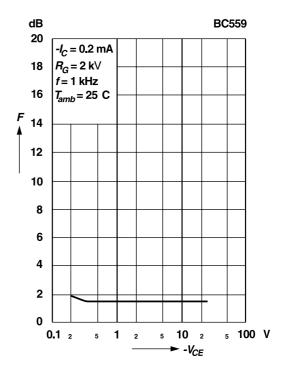




RATINGS AND CHARACTERISTIC CURVES BC556 THRU BC559



Noise figure versus collector current



Noise figure versus collector-emitter voltage



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